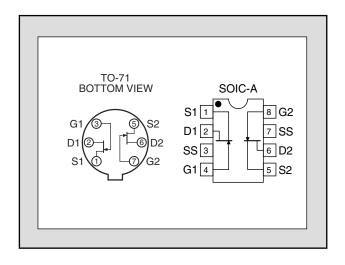


Linear Integrated Systems

FEATURES					
ULTRA LOW NOISE	e _n :	= 0.9nV/√Hz (typ)			
TIGHT MATCHING	$ V_G $	$ S_{S1-2} = 20 \text{mV max}$			
HIGH BREAKDOWN VOLTAGE	В	V_{GSS} = 40V max			
HIGH GAIN	SH GAIN $Y_{fs} = 20mS (typ)$				
LOW CAPACITANCE	OW CAPACITANCE 25pF typ				
IMPROVED SECOND SOURCE REPLACEMENT FOR 2SK389					
ABSOLUTE MAXIMUM RATINGS ¹					
@ 25 °C (unless otherwise stated)					
Maximum Temperatures					
Storage Temperature		-65 to +150 °C			
Operating Junction Temperature		-55 to +135 °C			
Maximum Power Dissipation					
Continuous Power Dissipation @ +125 °C)	400mW			
Maximum Currents					
Gate Forward Current		$I_{G(F)} = 10mA$			
Maximum Voltages					
Gate to Source		$V_{GSS} = 40V$			
Gate to Drain		$V_{GDS} = 40V$			

LSK389

ULTRA LOW NOISE MONOLITHIC DUAL N-CHANNEL JFET



*For equivalent single version, see LSK170 family.

MATCHING CHARACTERISTICS @ 25 °C (unless otherwise stated)

SYMBOL	CHARACTERISTIC	MIN	TYP	MAX	UNIT	CONDITIONS
$\left V_{GS1}-V_{GS2}\right $	Differential Gate to Source Cutoff Voltage			20	mV	V _{DS} = 10V, I _D = 1mA
	Gate to Source Saturation Current Ratio	0.9			ı	V _{DS} = 10V, V _{GS} = 0V

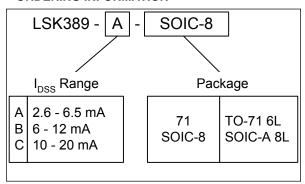
ELECTRICAL CHARACTERISTICS @ 25 °C (unless otherwise stated)

SYMBOL	CHARACTERISTIC		MIN	TYP	MAX	UNITS	CONDITIONS
BV_{GSS}	Gate to Source Breakdown Voltage		40			V	$V_{DS} = 0$, $I_{D} = 100 \mu A$
V _{GS(OFF)}	Gate to Source Pinch-off Vol	tage	0.15		2	V	$V_{DS} = 10V, I_D = 0.1 \mu A$
	Drain to Source Saturation Current	LSK389A	2.6		6.5	mA	V _{DS} = 10V, V _{GS} = 0
I_{DSS}		LSK389B	6		12		
		LSK389C	10		20		
I _{GSS}	Gate to Source Leakage Current				200	pА	V _{GS} = -30V, V _{DS} = 0

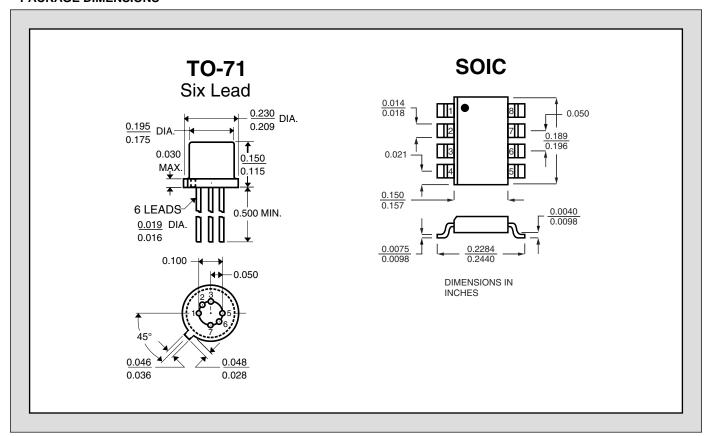
ELECTRICAL CHARACTERISTICS CONT. @ 25 °C (unless otherwise stated)

SYMBOL	CHARACTERISTIC	MIN	TYP	MAX	UNITS	CONDITIONS
Y _{fs}	Full Conduction Transconductance	8	20		mS	$V_{DS} = 10V$, $V_{GS} = 0$, $I_{DSS} = 3mA$, $f = 1kHz$
e _n	Noise Voltage		0.9	1.9	nV/√Hz	V_{DS} = 10V, I_{D} = 2mA, f = 1kHz, NBW = 1Hz
e _n	Noise Voltage		2.5	4	nV/√Hz	$V_{DS} = 10V$, $I_{D} = 2mA$, $f = 10Hz$, NBW = 1Hz
C _{ISS}	Common Source Input Capacitance		25		pF	$V_{DS} = 10V, V_{GS} = 0, f = 1MHz,$
C_{RSS}	Common Source Reverse Transfer Cap.		5.5		pF	$V_{DG} = 10V$, $I_{D} = 0$, $f = 1MHz$,

ORDERING INFORMATION



PACKAGE DIMENSIONS



Absolute maximum ratings are limiting values above which serviceability may be impaired.

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